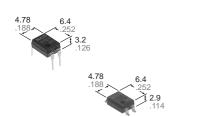


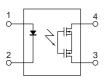


GU (General Use)-E Type 1-Channel (Form B) 4-pin Type

PhotoMOS RELAYS



mm inch

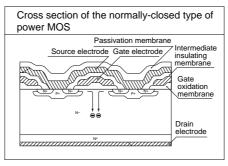


FEATURES

1. Low on resistance for normallyclosed type

This has been realized thanks to the builtin MOSFET processed by our proprietary method, DSD (Double-diffused and Selective Doping) method.

Cross section of the normally-closed type of power MOS



2. Reinforced insulation 5,000 V type More than 0.4 mm internal insulation distance between inputs and outputs. Conforms to EN41003, EN60950 (reinforced insulation).

3. Compact 4-pin DIP size

The device comes in a compact (W)6.4×(L)4.78×(H)3.2mm (W).252×(L).188×(H).126inch, 4-pin DIP size

4. Controls low-level analog signalsPhotoMOS relays feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without

5. High sensitivity, low ON resistance Can control a maximum 0.13 A load current with a 5 mA input current. Low ON resistance of 18Ω (AQY410EH). Stable operation because there are no metallic contact parts.

6. Low-level off state leakage current

TYPICAL APPLICATIONS

Modem

distortion.

- Telephone equipment
- Security equipment
- Sensors

TYPES

Туре	I/O isolation voltage	Output rating*			Pa	Packing quantity			
				Through hole terminal	Surface-mount terminal				
		Lood	Load Load voltage current			Tape and reel packing style			Tape and
				Tube pac	king style	Picked from the 1/2-pin side	Picked from the 3/4-pin side	Tube	reel
AC/DC type	Reinforced 5,000 V	350 V	130 mA	AQY410EH	AQY410EHA	AQY410EHAX	AQY410EHAZ	1 tube contains 100 pcs.	1,000 pcs.
		400 V	120 mA	AQY414EH	AQY414EHA	AQY414EHAX	AQY414EHAZ	1 batch contains 1,000 pcs.	

^{*}Indicate the peak AC and DC values.

Note: For space reasons, the initial letters of the product number "AQY", the SMD terminal shape indicator "A" and the package type indicator "X" and "Z" are omitted from the seal.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item		Symbol	AQY410EH (A)	AQY414EH (A)	Remarks
Input	LED forward current	I F	50 1		
	LED reverse voltage	VR	3		
	Peak forward current	IFP	1.	f = 100 Hz, Duty factor = 0.1%	
	Power dissipation	Pin	75 r		
Output	Load voltage (peak AC)	VL	350 V	400 V	
	Continuous load current	IL	0.13 A	0.12 A	
	Peak load current	Ipeak	0.4 A	0.3 A	100 ms (1 shot), V _L = DC
	Power dissipation	Pout	500 mW		
Total power dissipation		Р⊤	550		
I/O isolation voltage		Viso	5,000		
Tempe	erature Operating	Topr	−40°C to +85°C -	Non-condensing at low temperatures	
lim	nits Storage	T _{stg}	-40°C to +100°C		

AQY41OEH

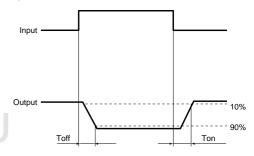
2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item			Symbol	AQY410EH (A)	AQY414EH (A)	Condition	
	LED operate	Typical		1.4 mA	1.3 mA	I. Mov	
	(OFF) current	Maximum	Foff	3.0 mA		⊢ I∟=Max.	
Innut	LED reverse	Minimum	l Fon	0.4	IL=Max.		
Input	(ON) current	Typical	IFon	1.3 mA	1.2 mA	il=iviax.	
	LED dropout	Typical	VF	1.14 (1.25 V	I _F = 5 mA		
	voltage	Maximum	\ \F	1.5 V			
	0	Typical	Ron	18Ω	26Ω	I _F = 0 mA I _L = Max.	
Output	On resistance	Maximum		25Ω	35Ω	Within 1 s on time	
·	Off state leak- age current	Maximum	Leak	10μΑ		I _F = 5 mA V _L = Max.	
	Operate (OFF) time*	Typical	T _{off}	1.0 ms	0.8 ms	I _F = 0 mA>5 mA	
		Maximum	I off	3.0 ms		I∟= Max.	
	Reverse (ON)	Typical	Ton	0.3 ms	0.2 ms	I _F = 5 mA>0 mA	
Transfer char-	time*	Maximum	I on	1.0 ms		I∟ = Max.	
acteristics	I/O conscitance	Typical	Ciso	0.8 pF		f =1MHz	
	I/O capacitance	Maximum	Oiso	1.5 pF		V _B =0	
	Initial I/O isolation resistance	Minimum	Riso	1,00	500 V DC		

Note: Recommendable LED forward current $I_F = 5$ to 10mA.

For type of connection, see page 32.

*Operate/Reverse time



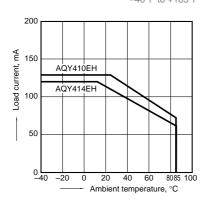
www.DataSheet4U

- **■** For Dimensions, see Page 27.
- For Schematic and Wiring Diagrams, see Page 32.
- For Cautions for Use, see Page 36.

REFERENCE DATA

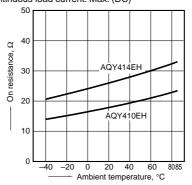
1. Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40° C to +85°C -40° F to +185°F

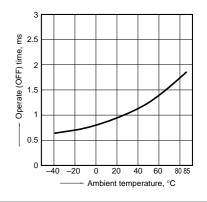


2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 3 and 4; LED current: 0 mA; Load voltage: Max.(DC); Continuous load current: Max. (DC)



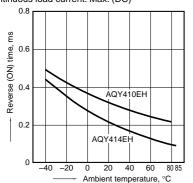
- 3. Operate (OFF) time vs. ambient temperature characteristics
- LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



AQY41OEH

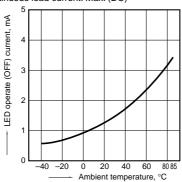
4. Reverse (ON) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



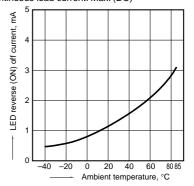
5. LED operate (OFF) current vs. ambient temperature characteristics

Load voltage: Max. (DC); Continuous load current: Max. (DC)



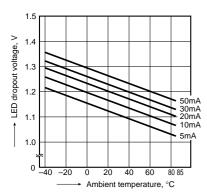
6. LED reverse (ON) current vs. ambient temperature characteristics

Load voltage: Max. (DC); Continuous load current: Max. (DC)



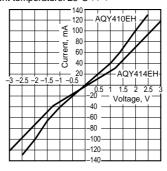
7. LED dropout voltage vs. ambient temperature characteristics

LED current: 5 to 50 mA



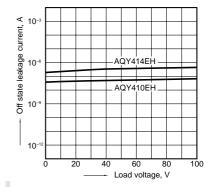
8. Voltage vs. current characteristics of out-put at MOS portion

Measured portion: between terminals 3 and 4; Ambient temperature: 25°C 77°F



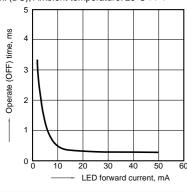
9. Off state leakage current

Measured portion: between terminals 3 and 4; Ambient temperature: 25°C 77°F



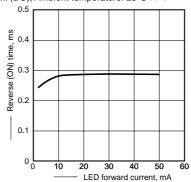
10. LED forward current vs. Operate (OFF) time characteristics

Measured portion: between terminals 3 and 4; Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



11. LED forward current vs. Reverse (ON) time characteristics

Measured portion: between terminals 3 and 4; Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: $25^{\circ}C$ $77^{\circ}F$



12. Applied voltage vs. output capacitance characteristics

Measured portion: between terminals 3 and 4; Frequency: 1 MHz; Ambient temperature: 25°C 77°F

